

SFM11-L THRU SFM18-L

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SFM11-L THRU SFM18-L

1.0A Surface Mount Super Fast Rectifiers 50V-600V

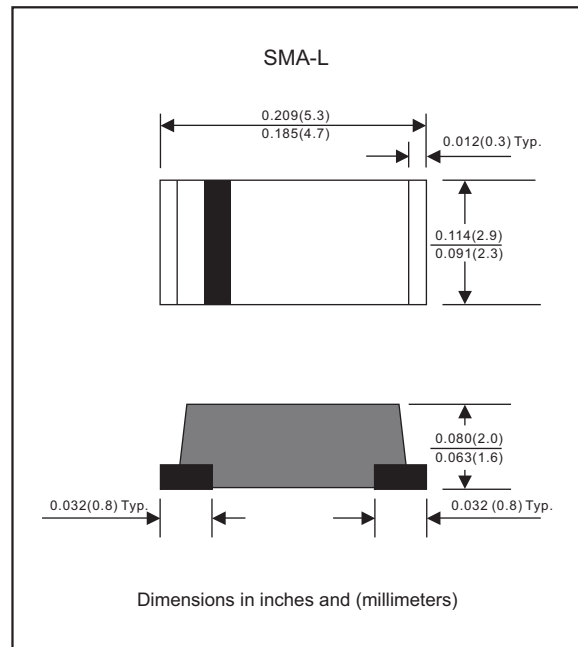
Features

- Batch process design, excellent power dissipation offers better reverse leakage current and thermal resistance
- Low profile surface mounted application in order to optimize board space
- High current capability
- Superfast recovery time for switching mode application
- High surge current capability
- Glass passivated chip junction
- Lead-free parts meet RoHS requirements
- Suffix "-H" indicates Halogen free parts, ex. SFM11-L-H

Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, SMA-L
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any
- Weight : Approximated 0.05 gram

Package outline



Maximum ratings (AT T_A=25°C unless otherwise noted)

PARAMETER	SYMBOLS	SFM11-L	SFM12-L	SFM13-L	SFM14-L	SFM15-L	SFM16-L	SFM17-L	SFM18-L	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	350	420	V
Maximum continuous reverse voltage	V _R	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current	I _o	1.0								A
Non-repetitive peak forward surge current 8.3ms single half sine-wave	I _{FSM}	30								A
Typical junction capacitance (Note 1)	C _J	10								pF
Operating junction temperature range	T _J	-55 to +150								°C
Storage temperature range	T _{STG}	-65 to +175								°C

Electrical characteristics (AT T_A=25°C unless otherwise noted)

PARAMETER	SYMBOLS	SFM11-L	SFM12-L	SFM13-L	SFM14-L	SFM15-L	SFM16-L	SFM17-L	SFM18-L	UNIT
Maximum instantaneous forward voltage at I _F =1.0A	V _F	0.95				1.25		1.70		V
Maximum reverse leakage current T _J =25°C at rated V _R T _J =125°C	I _R	5.0				100				μA μA
Maximum reverse recovery time (Note 2)	t _{rr}	35								ns

Thermal characteristics

PARAMETER	SYMBOLS	SFM11-L	SFM12-L	SFM13-L	SFM14-L	SFM15-L	SFM16-L	SFM17-L	SFM18-L	UNIT	
Typical thermal resistance junction to ambient (3)	R _{θJA}	49									°C/W
Typical thermal resistance junction to case(3)	R _{θJC}	29									°C/W

Notes 1: Measured at 1 MHz and applied reverse voltage of 4.0 VDC

2: Measured with I_F = 0.5 A, I_R = 1 A, I_{rr} = 0.25 A

3: Mounted on FR-4 PCB Copper, minimum recommended pad layout



Rating and characteristic curves (SFM11-L THRU SFM18-L)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

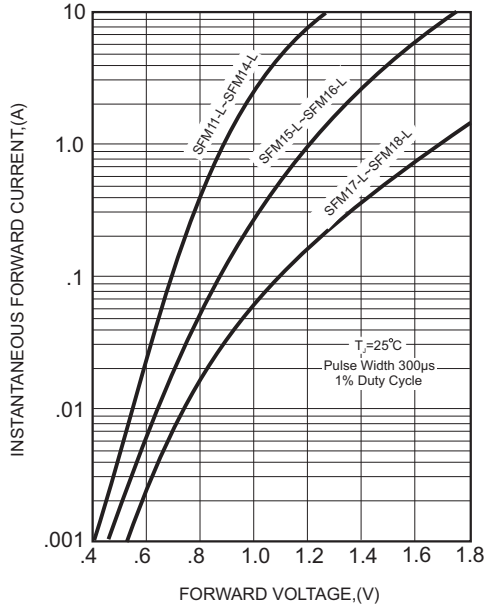


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

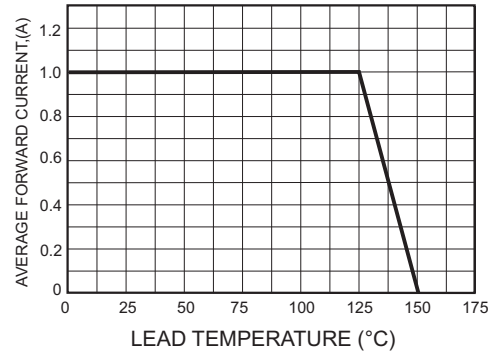


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

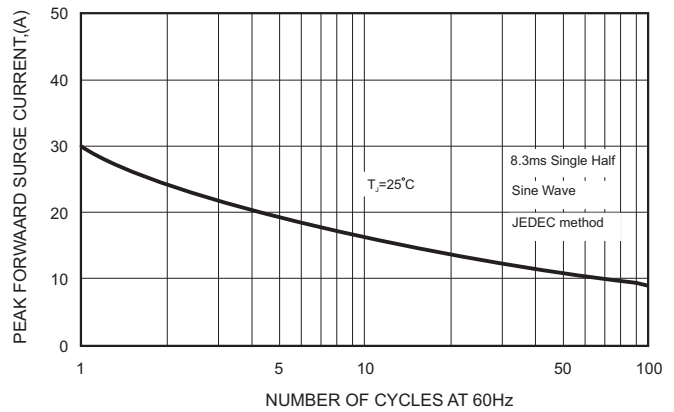
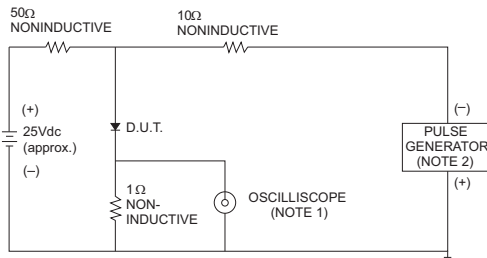


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



- NOTES: 1. Rise Time = 7ns max., Input Impedance = 1 megohm, 22pF.
 2. Rise Time = 10ns max., Source Impedance = 50 ohms.

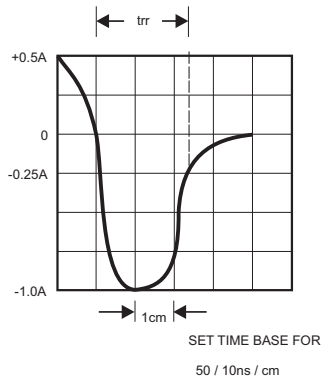
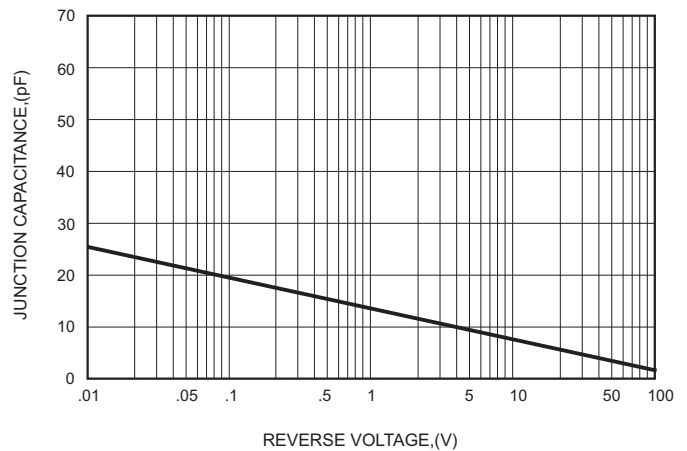




FIG.5-TYPICAL JUNCTION CAPACITANCE



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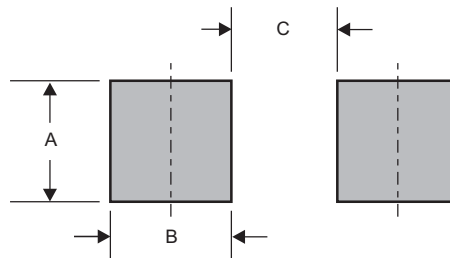
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

Marking

Type number	Marking code
SFM11-L	S11
SFM12-L	S12
SFM13-L	S13
SFM14-L	S14
SFM15-L	S15
SFM16-L	S16
SFM17-L	S17
SFM18-L	S18

Suggested solder pad layout

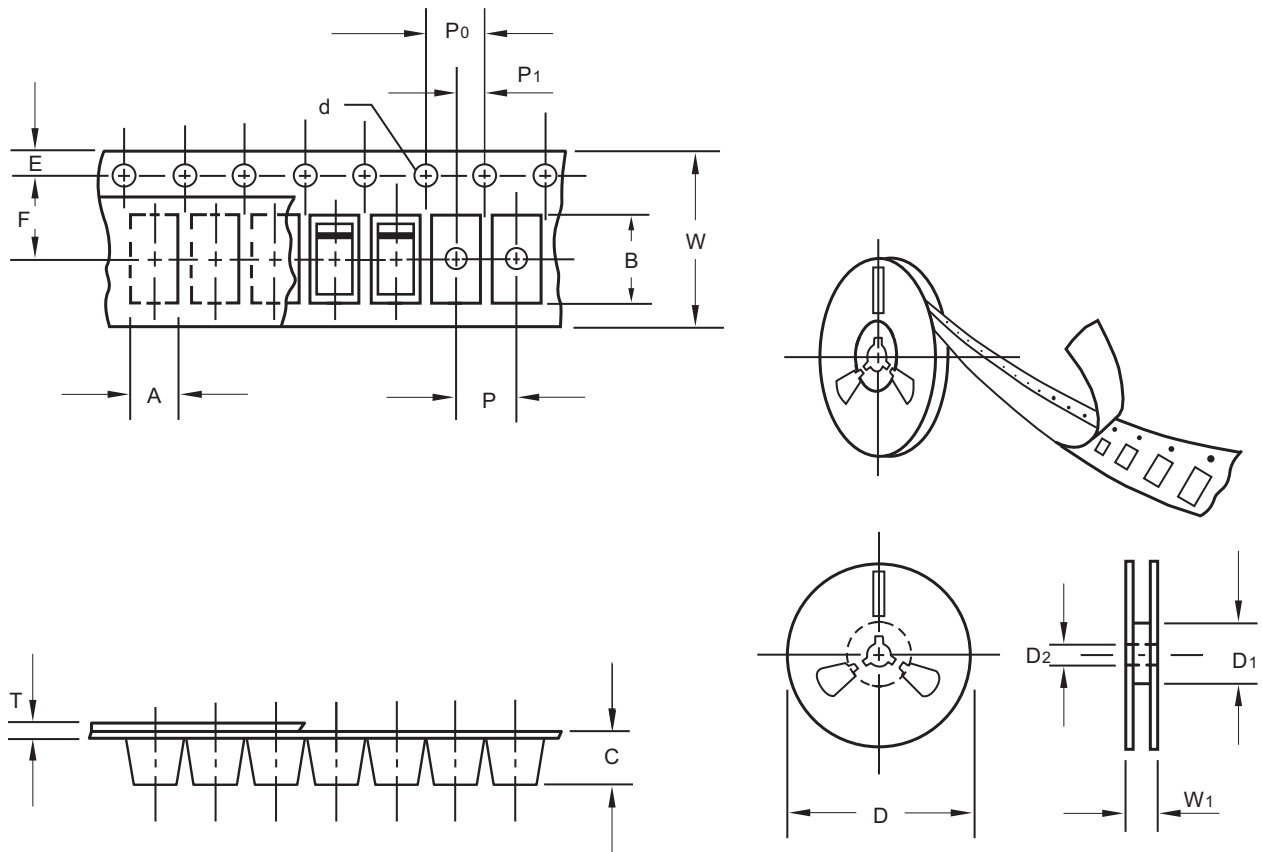


Dimensions in inches and (millimeters)

PACKAGE	A	B	C
SMA-L	0.110 (2.80)	0.059 (1.50)	0.110 (2.80)

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Packing information



unit:mm

Item	Symbol	Tolerance	SMA-L
Carrier width	A	0.1	2.90
Carrier length	B	0.1	5.50
Carrier depth	C	0.1	2.10
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	330.00
13" Reel inner diameter	D ₁	min	50.00
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D ₁	min	62.00
Feed hole diameter	D ₂	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	5.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P ₀	0.1	4.00
Embossment center	P ₁	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	12.00
Reel width	W ₁	1.0	18.00

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

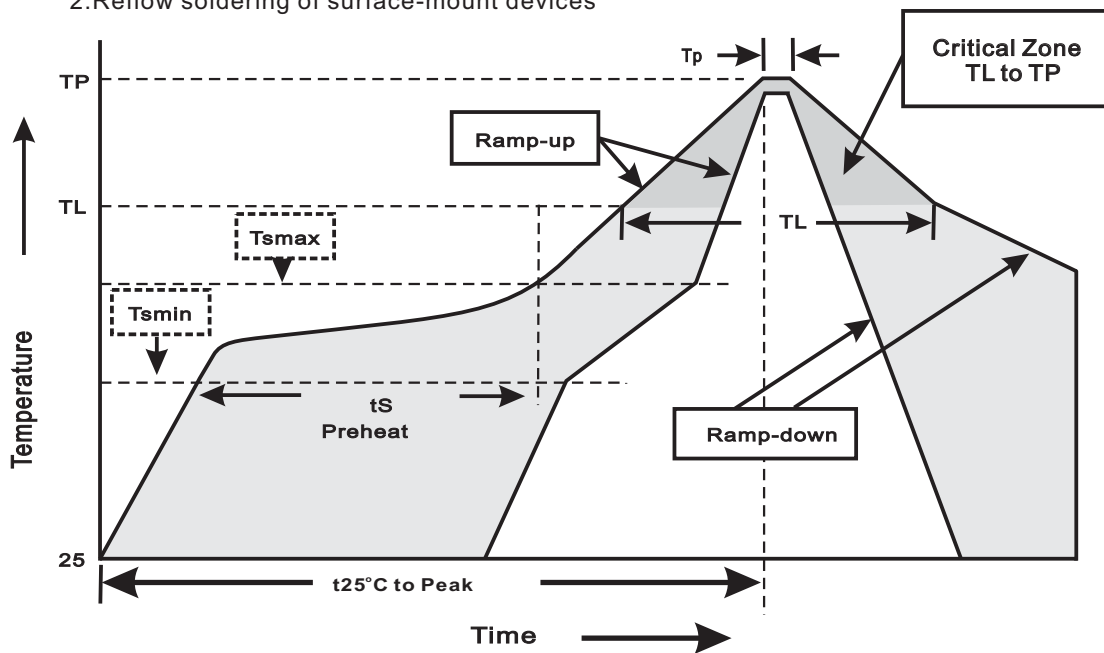
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Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMA-L	7"	2,000	4.0	20,000	183*155*183	178	382*356*392	160,000	15.5
	7"	2,000	4.0	10,000	180*180*80	178	440*410*220	100,000	13.0

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(TL to TP)	<3°C/sec
Preheat -Temperature Min(Tsmin) -Temperature Max(Tsmax) -Time(min to max)(ts)	150°C 200°C 60~120sec
Tsmax to TL -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(TL) -Time(tL)	217°C 60~260sec
Peak Temperature(TP)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(tp)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

SFM11-L THRU SFM18-L**High reliability test capabilities**

Item Test	Conditions	Reference
1. Solder Resistance	at 260±5°C for 10±2sec.	MIL-STD-750D METHOD-2031
2. Solderability	at 245±5°C for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_R=80\%$ rate at $T_J=150^\circ\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at $T_A=25^\circ\text{C}$ for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	$T_A = 25^\circ\text{C}$, $I_F = I_O$ On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	15P _{SIG} at $T_A=121^\circ\text{C}$ for 4 hrs.	JESD22-A102
7. Temperature Cycling	-55°C to +125°C dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Forward Surge	8.3ms single half sine-wave , one surge.	MIL-STD-750D METHOD-4066-2
9. Humidity	at $T_A=85^\circ\text{C}$, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
10. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031